

SiC Schottky Barrier Diode

V_R	650V
I _F	10A
Q_{C}	24nC

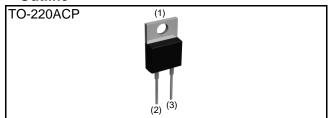
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

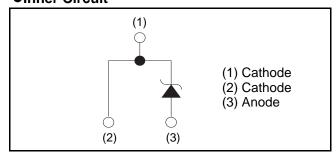
Construction

Silicon carbide epitaxial planar type

●Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Type Ba	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS310AH

● Absolute Maximum Ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	l current (T _c =135°C)	I _F	10	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		82	A
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	69	A
current	PW=10μs square, T _j =25°C		300	А
Repetitive peak forward current		I _{FRM}	45 *1	А
1≦PW≦10ms, T _j =25°C		.∫ i²dt	33	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		J I-at	23	A ² s
Total power disspation		P_{D}	71 *²	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter Symbol Conditions	Cymbol	Conditions	Values			l lm:t
	Conditions	Min.	Тур.	Max.	Unit	
DC blocking voltage	V_{DC}	I _R =50μA	650	-	-	V
		I _F =10A,T _j =25°C	-	1.35	1.50	V
Forward voltage	V_{F}	I _F =10A,T _j =150°C	-	1.44	1.71	V
		I _F =10A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.03	50	μА
		V _R =650V,T _j =150°C	-	2	200	μΑ
		V _R =650V,T _j =175°C	-	6	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	500	-	pF
		V _R =650V,f=1MHz	-	46	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	24	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	15	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	130	-	mJ

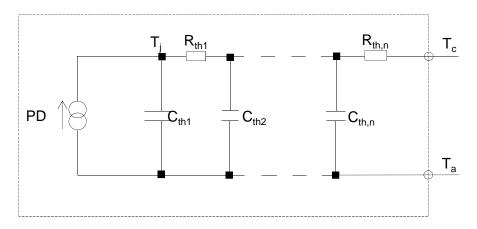
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	1.5	2.1	°C/W

● Typical Transient Thermal Characteristics

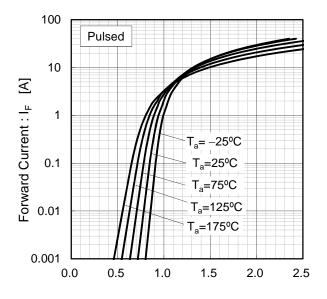
Symbol	Value	Unit
R _{th1}	1.55E-02	
R _{th2}	1.46E-01	K/W
R _{th3}	1.32E+00	

Symbol	Value	Unit
C _{th1}	2.63E-04	
C _{th2}	1.00E-03	Ws/K
C _{th3}	2.13E-03	



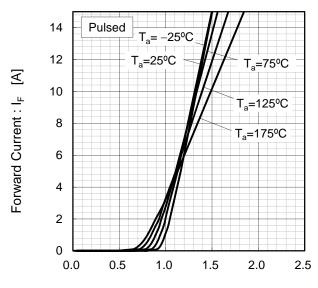
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



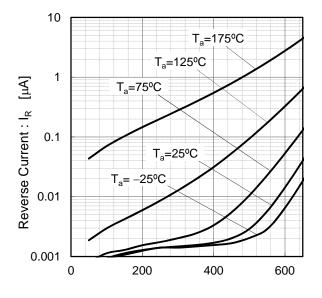
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



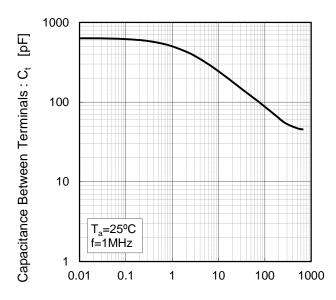
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

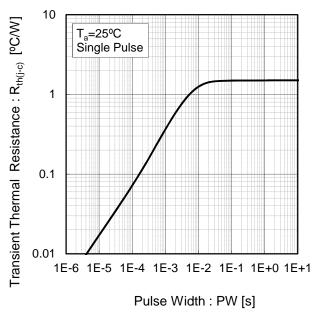
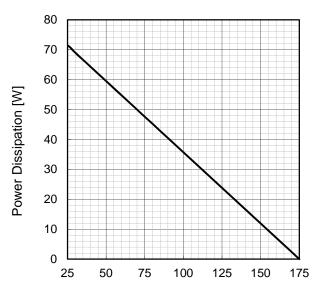
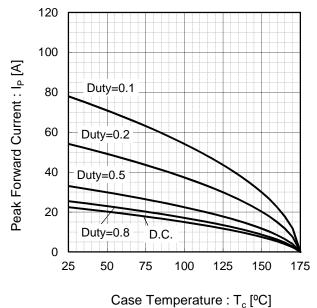


Fig.6 Power Dissipation



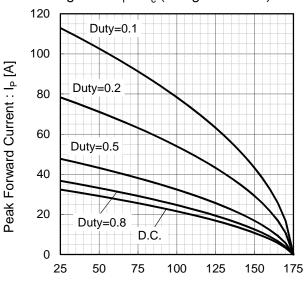
Case Temperature : T_c [°C]

Fig.7*3 Maximum peak forward current derating curve I_P - T_c



*3 Based on max Vf, max $R_{\text{th(j-c)}}$ Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)

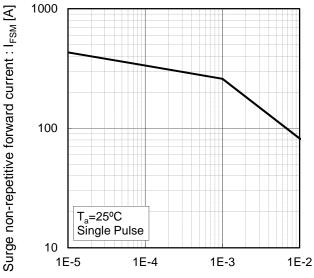


Case Temperature : T_c [°C]

 $^{*}4$ Based on typ Vf, typ $R_{\text{th(j-c)}}$ Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

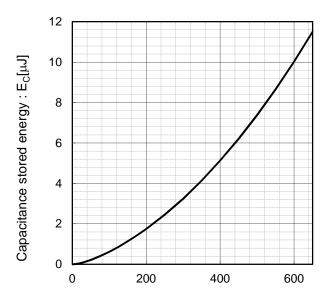
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



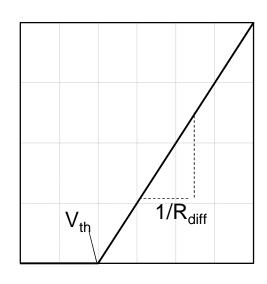
Pulse Width: PW [s]

Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Fig.11 Equivalent forward current curve



Forward Voltage : V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a_0	9.66E-01	V
a ₁	- 1.10E-03	V/°C
b_0	3.52E-02	Ω
b ₁	7.46E-05	Ω/°C
b ₂	7.68E-07	Ω /°C ²

 T_i in °C; -55 °C < T_i < 175°C; I_F < 20A

Forward Current: IF

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SCS310AHG - Web Page

Distribution Inventory

Part Number	SCS310AHG
Package	TO-220ACP
Unit Quantity	1000
Minimum Package Quantity	50
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes